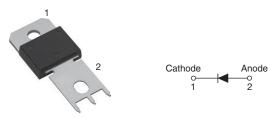
VS-85EPF12 Soft Recovery Series

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Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 85 A



PowerTab[®]

PRIMARY CHARACTERISTICS				
I _{F(AV)}	85 A			
V _R	1200 V			
V _F at I _F	1.36 V			
I _{FSM}	1250 A			
t _{rr}	95 ns			
T _J max.	150 °C			
Snap factor	0.5			
Package	PowerTab [®]			
Circuit configuration	Single			

FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operating junction temperature
- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met
- Screw mounting only
 Designed and qualified according to JEDEC[®]-JESD 47
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-85EPF12 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions. Available in the new PowerTab package, this new series is suitable for a large range of applications combining excellent die to footprint ratio and sturdiness connectivity for use in high current environments.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rect. conduction 50 % duty cycle at $T_C = 85 \text{ °C}$	85	^	
I _{F(RMS)}		160	A	
V _{RRM}		1200	V	
I _{FSM}		1250	A	
V _F	100 A, T _J = 25 °C	1.4	V	
t _{rr}	1 A, - 100 A/μs	95	ns	
TJ	Range	-40 to +150	°C	

VOLTAGE RATINGS					
TYPE NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-85EPF12	1200	1300	15		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	DL TEST CONDITIONS VALUES		UNITS
Maximum average forward current	I _{F(AV)}	$T_{C} = 85 \text{ °C}, 180^{\circ}$ conduction half sine wave	85	
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V _{RRM} applied	1100	А
		10 ms sine pulse, no voltage reapplied	1250	7
Maximum I ² t for fusing I ² t		10 ms sine pulse, rated V _{RRM} applied 5000	5000	A ² s
		10 ms sine pulse, no voltage reapplied	7000	A-S
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	70 000	A²√s

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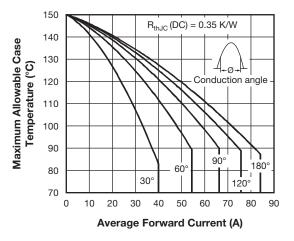
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	85 A, T _J = 25 °C		1.36	V
Forward slope resistance	r _t	T _J = 150 °C		4.03	mΩ
Threshold voltage	V _{F(TO)}			0.87	V
		$T_J = 25 \ ^\circ C$	V_{R} = Rated V_{RRM}	0.1	mA
Maximum reverse leakage current	I _{RM}	T _J = 150 °C		15	ША

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Reverse recovery time	t _{rr}	In at 85 Anic	480	ns	I _{FM} t
Reverse recovery current	I _{rr}	l _F at 85 A _{pk} 25 A/µs	7.1	А	
Reverse recovery charge	Q _{rr}	25 °C	2.1	μC	
Snap factor	S		0.5		I I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and st temperature range	orage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resista junction to case	nce,	R _{thJC}	DC operation	0.35	
Maximum thermal resista junction to ambient	nce,	R _{thJA}		40	°C/W
Typical thermal resistance case to heatsink	e,	R _{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
Approximate weight				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style PowerTab [®]	85EPF12	



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Fig. 1 - Current Rating Characteristics

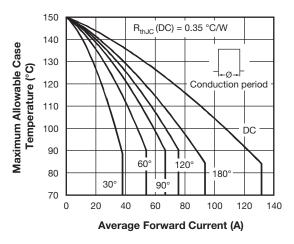


Fig. 2 - Current Rating Characteristics

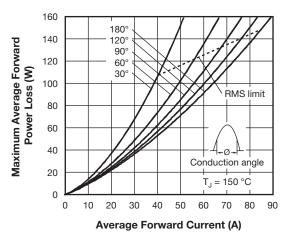


Fig. 3 - Forward Power Loss Characteristics

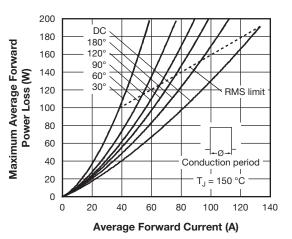
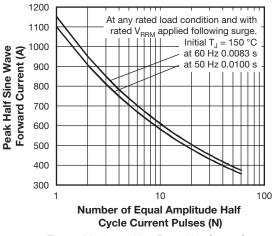
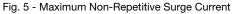


Fig. 4 - Forward Power Loss Characteristics





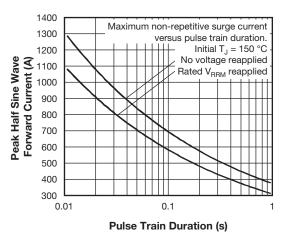


Fig. 6 - Maximum Non-Repetitive Surge Current

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= 80 A FM

= 40 A

I_{FM} = 20 A

I_{FM} = 10 A

160

200

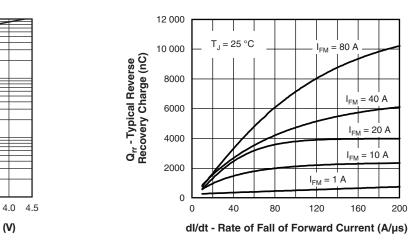


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

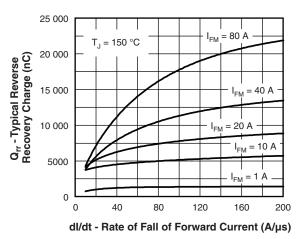


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

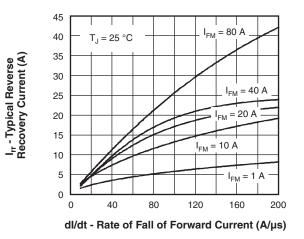
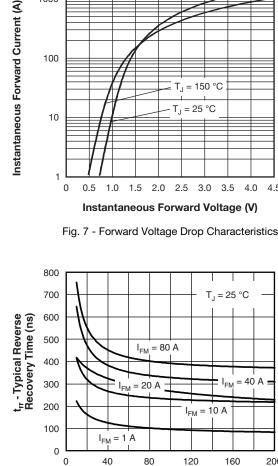


Fig. 12 - Recovery Current Characteristics, T_J = 25 $^\circ\text{C}$



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1000

100

dl/dt - Rate of Fall of Forward Current (A/µs) Fig. 8 - Recovery Time Characteristics, $T_J = 25 \ ^{\circ}C$

200

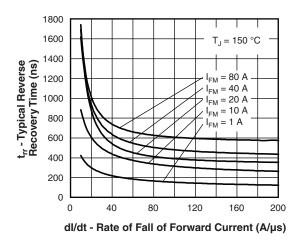


Fig. 9 - Recovery Time Characteristics, $T_J = 150$ °C

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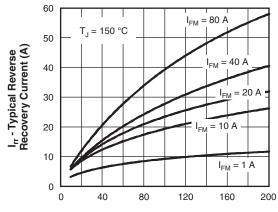
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dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

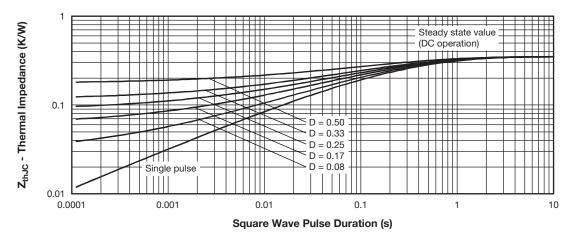


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

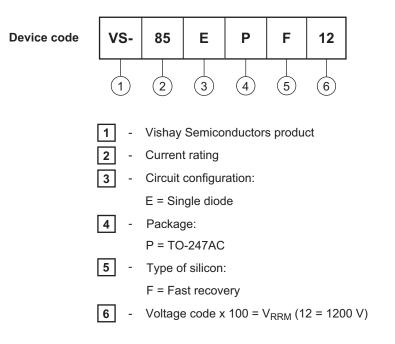
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ORDERING INFORMATION TABLE



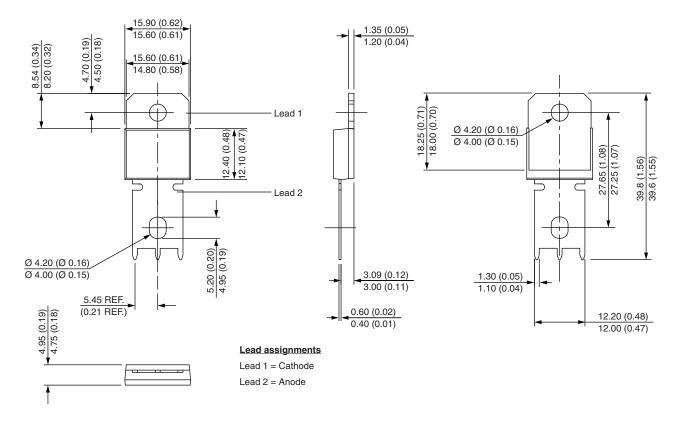
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95240		
Part marking information	www.vishay.com/doc?95370		
Application note	www.vishay.com/doc?95179		



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DIMENSIONS in millimeters (inches)





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